Amorphous interlayers between crystalline grains in ferromagnetic ZnO films

B.B. Straumal, S.G. Protasova, A.A. Mazilikin, B. Baretzky, A.A. Myatiev, P.B. Straumal, Th. Tietze, G. Schütz, E. Goering

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The nanograined thin films of undoped ZnO were synthesized by the wet chemistry method. Films consist of the equiaxial nanograins, and possess ferromagnetic properties. Structural investigations by the XRD and HREM reveal that the crystalline wurtzite grains do not contact each other and are completely surrounded by a layer of amorphous phase. It forms a kind of continuous foam-like network, where the amorphous intergranular phase amount could be increased by the synthesis parameters. Simultaneously, the saturation magnetization increases as well.

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1. Introduction

Transparent semiconducting ZnO would be a very attractive material for future spintronics applications, if it simultaneously possesses ferromagnetic (FM) properties [1–3]. Based on the p–d Zener-like model Th. Dietl et al. theoretically predicted that ZnO doped by the “magnetic” atoms like Mn, Co or Fe can become ferromagnetic at room temperature (RT) and above [4]. Summarizing 10 years effort of the investigations of diluted magnetic semiconductors and oxides, Th. Dietl underlined that the data on pure and doped ZnO remain quite contradictory [5]. Obviously, the bulk ZnO with uniformly distributed Mn atoms (or other “magnetic” dopants) is not ferromagnetic [5]. In order to elucidate the dependence of RT ferromagnetism on the microstructure in ZnO, we have recently analyzed a large series of experimental publications with respect to the present specific grain boundary (GB) area, i.e. the ratio of GB area to grain volume $S_{GB}$ [6]. FM only appears, if $S_{GB}$ exceeds a certain threshold value $S_{th}$. If the density of GB network is high enough, ZnO becomes ferromagnetic even without dopants [7,8]. Thus $S_{th}=(2±4) \times 10^{5} \text{m}^{-2}$ for the Mn-doped ZnO and $S_{th}=(7±3) \times 10^{7} \text{m}^{-2}$ for pure ZnO [6]. We observed recently that the crystalline wurtzite grains in FM Mn-doped ZnO are separated by amorphous layers [9,10]. The thickness of these layers increases with Mn contents [9,10]. The main goal of this work is to investigate the structure of grain boundaries and/or that of intergranular layers in pure nanograined ZnO films and to search for structural reasons of their FM behavior.

2. Experimental

ZnO thin films consisting of dense equiaxial nanograins were produced by using the novel method of liquid ceramics [11]. Zinc (II) butanoate diluted in the organic solvent with zinc concentrations between 1 and 4 kg/m$^3$ was used as a precursor. The butanoate precursor was deposited on (102) oriented sapphire single crystals. Drying at 100 °C in air (about 30 min) was followed by thermal pyrolysis in an electrical furnace in argon (1) at 650 °C, 0.5 h and (2) at 550 °C, 24 h. A similar method was recently proposed for zinc oleates [12]. The films were transparent and reveal sometimes a very slight greenish furnish. The thickness of the films was (1) 690 nm and (2) 370 nm, respectively. The film thickness was determined by means of electron-probe microanalysis (EPMA) and edge-on transmission electron microscopy (TEM). The presence of other magnetic impurities as Fe, Co, Mn and Ni was measured by atomic absorption spectroscopy in a Perkin-Elmer spectrometer and by electron-probe microanalysis (EPMA) and remained below 0.001 at%. EPMA investigations were carried out in a Tescan Vega TSS5130 MM microscope equipped by the LINK energy-dispersive spectrometer produced by Oxford Instruments. TEM investigations were carried out on a Jeol JEM-4000FX microscope at an accelerating voltage of 400 kV. The TEM samples were prepared by FIB technique. X-ray diffraction (XRD) data were obtained on a Siemens diffractometer (Co Ka radiation).
3. Results and discussion

Fig. 1a shows the magnetization $M(H)$ curves for ZnO thin films (1) and (2) measured together with sapphire substrate. The $M(H)$ values in Fig. 1a are normalized for the same area of the films and given in emu/cm$^2$. In Fig. 1b the central parts (low fields) magnetization curves for the films (1) and (2) are shown without input of sapphire substrate and given in emu/cm$^3$. In Fig. 1c the magnetization curve for the film (2) is shown without substrate input, the $M(H)$ values are given in $\mu$Bohr/f.u. The magnetization curves clearly show the pronounced ferromagnetism indicated by the saturation of magnetization (above the applied field ~1 T). $M(H)$ is different for two ZnO films synthesized in different conditions: $M_s (1) = 0.1$ emu/cm$^3$ and $M_s (2) = 0.7$ emu/cm$^3$. For the film (1) $M_s = 27 \cdot 10^{-6}$ emu/cm$^2$ is very close to the substrate input of about $24 \cdot 10^{-6}$ emu/cm$^2$. The saturation magnetization of the film (2) corresponds to about $2 \cdot 10^{-3}$ $\mu$Bohr/f.u. It is, therefore, comparable with previously obtained data [6]. The inset shows the central part of the magnetization curve for the sample (2). Both branches of magnetization curve are very close to each other at zero field. However, the coercivity is about 0.01 T at the applied field of 0.2–0.4 T. Thus, similar to our previous work [6] we observe a clear saturable ferromagnetic-like RT behavior in the pure, undoped ZnO without any magnetic impurity.

Fig. 2a shows the bright field high-resolution TEM micrograph of ZnO film (1) annealed in argon at 650°C for 0.5 h. This sample possesses very weak FM with $M_s (1) = 27 \cdot 10^{-6}$ emu/cm$^2$ (Fig. 1a). A clear crystalline ZnO structure is directly observable in the bright field images for each grain, which are separated from each other by thin amorphous layers. (b) The respective selected area electron diffraction (SAED) pattern. The positions of wurtzite reflections and weak amorphous halo are shown. (c) X-rays diffraction spectrum. The background is subtracted and the spectrum is deconvoluted (three thin lines). It consists of three wurtzite peaks 110, 002 and 101. The halo from the amorphous phase is negligible.
Fig. 3a contains the bright field high-resolution TEM micrograph of the ZnO film (2) annealed in argon at 550 °C, 24 h. This film is ferromagnetic with $M_\text{s} = 75\cdot10^{-3}$ emu/cm$^3$ (Fig. 1a) or $2\cdot10^{-3}$ μB/μ. (Fig. 1b). Crystalline ZnO grains with wurtzite structure are surrounded by the broad amorphous areas. The SAED pattern (Fig. 3b) contains the wurtzite reflections and strong amorphous halo. The X-rays diffraction spectrum (Fig. 3c) consists of the halo from the amorphous phase (low peak in the middle) which is superimposed over the 002 and 101 peaks of crystalline wurtzite ZnO phase. The 101 peak is weak in comparison with that in the sample (1), Fig. 2c. The peak 100 is completely absent. It means that the grains in sample (1) are oriented randomly and sample (2) is textured. Comparing the integral intensities of two crystalline peaks and of the amorphous halo in Fig. 3c allows a rough estimation of the amount of amorphous phase, which is about 15%. Therefore, the $M_\text{s}$ definitely increases with increasing amount of intergranular amorphous phase. In our previous work we demonstrated that the $M_\text{s}$ dependence on Mn concentration is different in (nanograined) Mn:ZnO samples manufactured with different methods. For example, $M_\text{s}$ drastically changes with changing topology of the GB network in the Mn-doped zinc oxide [9]. Most probably, the ferromagnetism in ZnO is not only driven by the defects. Moreover, the proper combination and topology of interpenetrating crystalline and amorphous phases is needed for the ferromagnetism in pure ZnO.

The defects and non-uniformity of spatial distribution of dopant atoms in ZnO are frequently discussed as a possible reason for the FM behavior [5 and references therein]. However, even without dopants ZnO remain a two-component system. And it is known that in the two- and multicomponent systems the composition of intergranular layers differs from the bulk composition [13,14]. This difference is even more pronounced in case if the GBs are thicker than one atomic monolayer [15]. In other words, the observed amorphous regions separating the crystalline grains with wurtzite structure can be oxygen-deficient. These interconnected amorphous layers form the “ferromagnetic GB foam” in zinc oxide.

4. Conclusions

Thus, we can conclude that (1) ferromagnetic behavior can be observed in pure ZnO even without magnetic dopants, (2) the presence of a dense grain boundary network is a necessary but not sufficient condition for the ferromagnetism in pure ZnO, (3) the microstructure of intergranular layers in ZnO can be tailored by adjusting the synthesis conditions, (4) saturation magnetization $M_\text{s}$ depends on the structure of intergranular layers in ZnO, (5) $M_\text{s}$ increases with increasing amount of intergranular amorphous phase, (6) most probably the proper combination of interpenetrating crystalline and amorphous phases is the condition for the ferromagnetism in pure ZnO.

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